

QM15DX-24

MEDIUM POWER SWITCHING USE
INSULATED TYPE

QM15DX-24



- **IC** Collector current **15A**
- **V_{CEX}** Collector-emitter voltage **1200V**
- **h_{FE}** DC current gain **75**
- **Insulated Type**
- **UL Recognized**

Yellow Card No. E80276 (N)

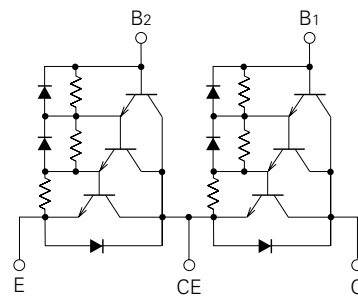
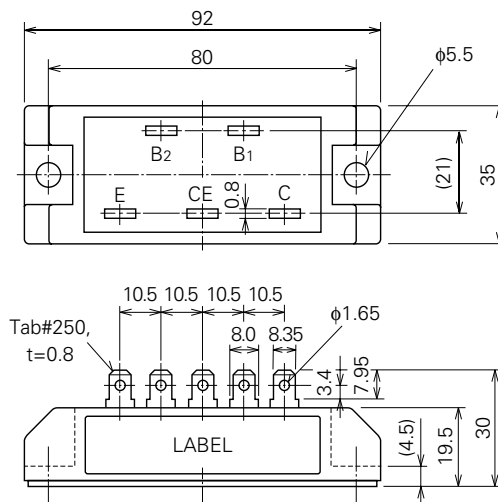
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APPLICATION

AC motor controllers, UPS, DC motor controllers, NC equipment, Welders

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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ABSOLUTE MAXIMUM RATINGS (Tj=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
VCEX (SUS)	Collector-emitter voltage	IC=1A, VEB=2V	1200	V
VCEX	Collector-emitter voltage	VEB=2V	1200	V
VCBO	Collector-base voltage	Emitter open	1200	V
VEBO	Emitter-base voltage	Collector open	7	V
IC	Collector current	DC	15	A
-IC	Collector reverse current	DC (forward diode current)	15	A
PC	Collector dissipation	Tc=25°C	150	W
IB	Base current	DC	1	A
-ICSM	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	150	A
Tj	Junction temperature		-40~+150	°C
Tstg	Storage temperature		-40~+125	°C
Viso	Isolation voltage	Charged part to case, AC for 1 minute	2500	V
—	Mounting torque	Mounting screw M5	1.47~1.96	N·m
—	Weight	Typical value	15~20	kg·cm
—	Weight	Typical value	155	g

ELECTRICAL CHARACTERISTICS (Tj=25°C, unless otherwise noted)

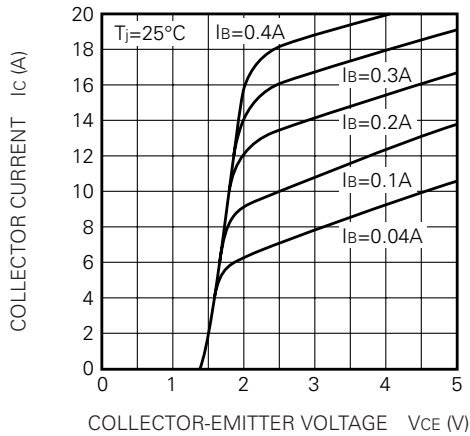
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
ICEX	Collector cutoff current	VCE=1200V, VEB=2V	—	—	2.0	mA
ICBO	Collector cutoff current	VCB=1200V, Emitter open	—	—	2.0	mA
IEBO	Emitter cutoff current	VEB=7V	—	—	100	mA
VCE (sat)	Collector-emitter saturation voltage	IC=15A, IB=0.3A	—	—	3.0	V
VBE (sat)	Base-emitter saturation voltage		—	—	3.5	V
-VCEO	Collector-emitter reverse voltage	-IC=15A (diode forward voltage)	—	—	1.5	V
hFE	DC current gain	IC=15A, VCE=5V	75	—	—	—
ton	Switching time	VCC=600V, IC=15A, IB1=-IB2=0.3A	—	—	2.5	μs
ts			—	—	15	μs
tf			—	—	3.0	μs
Rth (j-c) Q	Thermal resistance (junction to case)	Transistor part (per 1/2 module)	—	—	0.8	°C/W
Rth (j-c) R		Diode part (per 1/2 module)	—	—	1.2	°C/W
Rth (c-f)	Contact thermal resistance (case to fin)	Conductive grease applied (per 1/2 module)	—	—	0.25	°C/W

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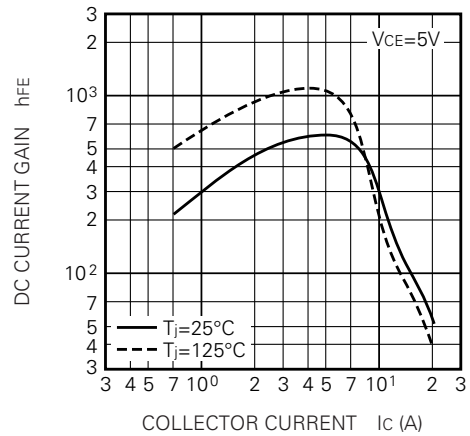
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PERFORMANCE CURVES

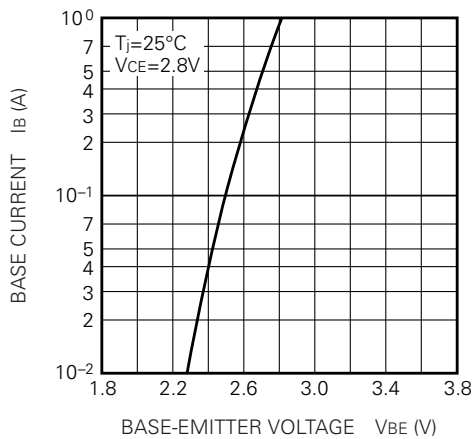
COMMON EMITTER OUTPUT CHARACTERISTICS (TYPICAL)



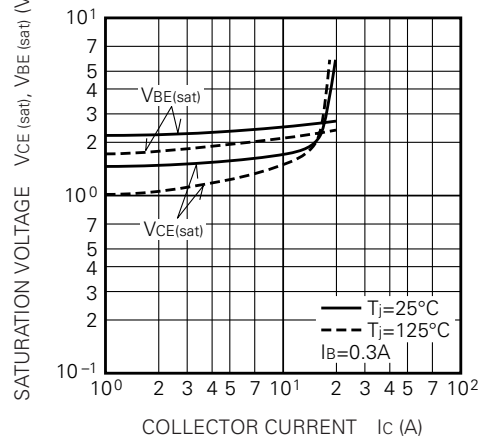
DC CURRENT GAIN VS. COLLECTOR CURRENT (TYPICAL)



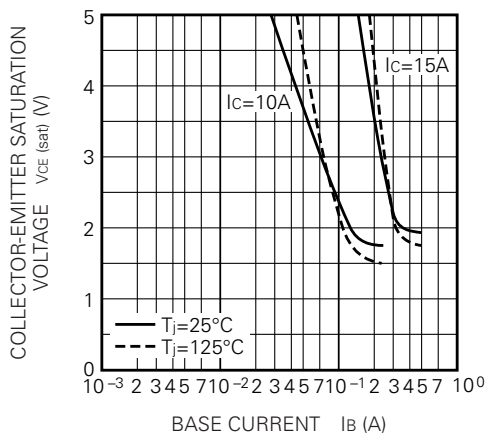
COMMON EMITTER INPUT CHARACTERISTIC (TYPICAL)



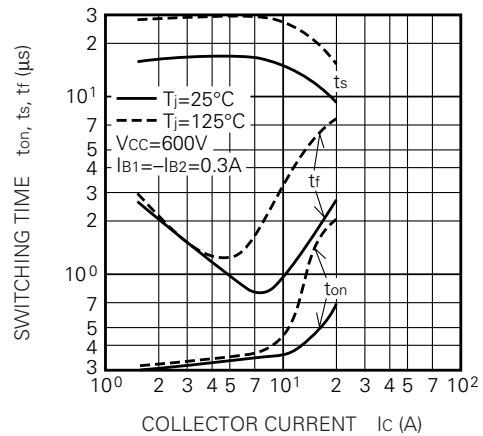
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



COLLECTOR-EMITTER SATURATION VOLTAGE (TYPICAL)



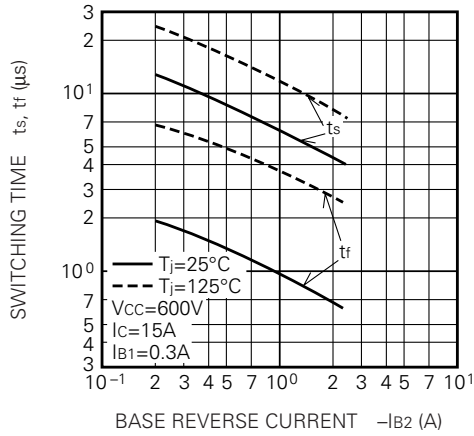
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



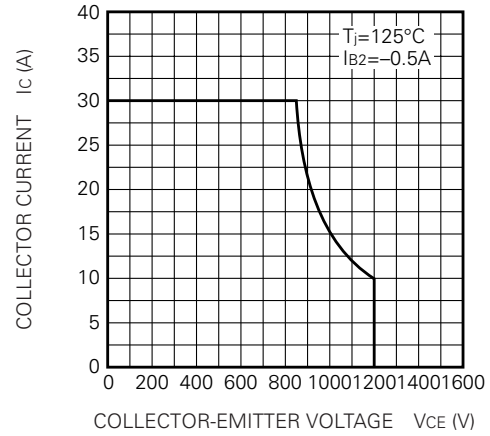
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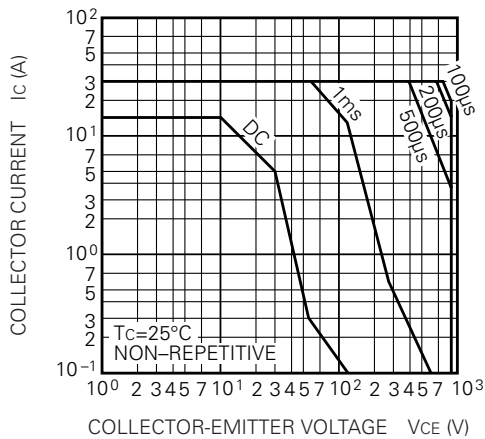
SWITCHING TIME VS. BASE CURRENT (TYPICAL)



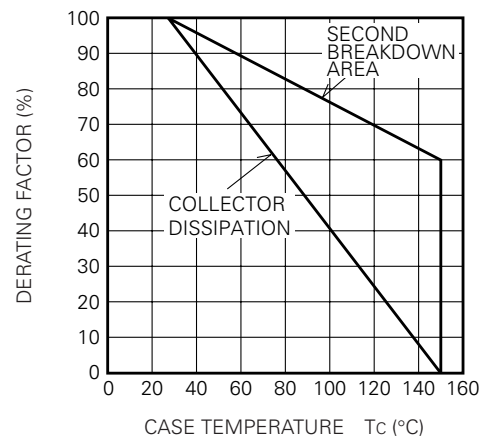
REVERSE BIAS SAFE OPERATING AREA



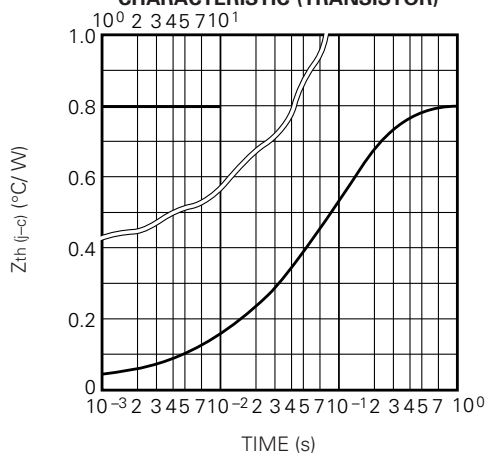
FORWARD BIAS SAFE OPERATING AREA



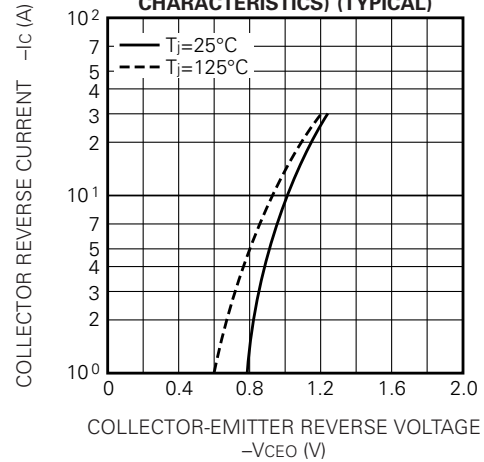
DERATING FACTOR OF F. B. S. O. A.



TRANSIENT THERMAL IMPEDANCE CHARACTERISTIC (TRANSISTOR)



REVERSE COLLECTOR CURRENT VS. COLLECTOR-EMITTER REVERSE VOLTAGE (DIODE FORWARD CHARACTERISTICS) (TYPICAL)



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